Unitized Semiconductor Devices - Page 1 of 1



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## Inclosure Material:

Metal

# **Overall Length:**

Between 0.165 inches and 0.185 inches

# **Terminal Length:**

0.500 inches

## **Overall Diameter:**

Between 0.335 inches and 0.370 inches

### **Component Name And Quantity:**

2 transistor

### **Mounting Method:**

Terminal

#### **Terminal Circle Diameter:**

Between 0.190 inches and 0.210 inches

#### Features Provided:

Hermetically sealed case

# Semiconductor Material:

Silicon all transistor

### Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage/static/emitter open all transistor and 60.0 collector to emitter voltage/static/base open all transistor and 7.0

emitter to base voltage, static, collector open all transistor

# **Current Rating Per Characteristic:**

10.00 milliamperes source cutoff current all transistor

## **Power Rating Per Characteristic:**

250.0 milliwatts small-signal input power, common-collector preset 2nd transistor

### Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius ambient air

#### **Special Features:**

All transistor junction pattern arrangement: npn

### **Terminal Type And Quantity:**

6 uninsulated wire lead

#### Shelf Life:

N/a

#### Unit Of Measure:

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### Demilitarization:

Yes - demil/mli

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